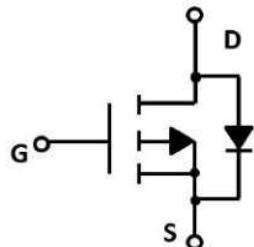
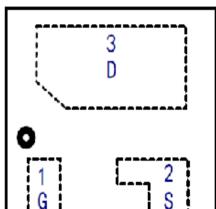


**TM07P02AF3**
**P-Channel Enhancement Mosfet**

<b>General Description</b> <ul style="list-style-type: none"> <li>Low <math>R_{DS(ON)}</math></li> <li>RoHS and Halogen-Free Compliant</li> </ul> <b>Applications</b> <ul style="list-style-type: none"> <li>Load switch</li> <li>PWM</li> </ul>	<b>General Features</b> <p> <math>V_{DS} = -20\text{ V}</math> <math>I_D = -7.0\text{ A}</math>  <math>R_{DS(ON)} = 24\text{ m}\Omega</math> (typ.) @ <math>V_{GS} = -4.5\text{ V}</math>          100% UIS Tested          100% <math>R_g</math> Tested       </p>
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**AF3: DFN1.5x1.5-3L**

**Marking: 07P02**
**Absolute Maximum Ratings** ( $T_A = 25^\circ\text{C}$  Unless Otherwise Noted)

Symbol	Parameter	Max.	Units
$V_{DSS}$	Drain-Source Voltage	-20	V
$V_{GSS}$	Gate-Source Voltage	$\pm 12$	V
$I_D$	Continuous Drain Current	$T_A = 25^\circ\text{C}$	A
		$T_A = 100^\circ\text{C}$	A
$I_{DM}$	Pulsed Drain Current <sup>note1</sup>	-28	A
$P_D$	Power Dissipation	$T_A = 25^\circ\text{C}$	W
$R_{\theta JA}$	Thermal Resistance, Junction to Case	70	$^\circ\text{C}/\text{W}$
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to +150	$^\circ\text{C}$

**Electrical Characteristics** ( $T_J=25^\circ\text{C}$  unless otherwise specified)

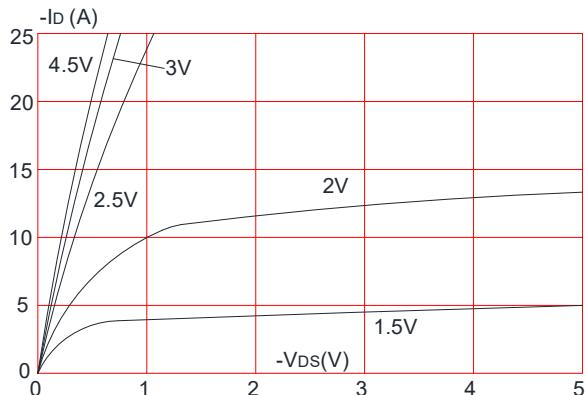
Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
<b>Off Characteristic</b>						
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0\text{V}$ , $I_D= -250\mu\text{A}$	-20	-	-	V
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS}= -20\text{V}$ , $V_{GS}=0\text{V}$ ,	-	-	-1	$\mu\text{A}$
$I_{GSS}$	Gate to Body Leakage Current	$V_{DS}=0\text{V}$ , $V_{GS}= \pm 12\text{V}$	-	-	$\pm 100$	nA
<b>On Characteristics</b>						
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$ , $I_D= -250\mu\text{A}$	-0.4	-0.7	-1.0	V
$R_{DS(\text{on})}$ note2	Static Drain-Source on-Resistance	$V_{GS}= -4.5\text{V}$ , $I_D= -7\text{A}$	-	24	33	$\text{m}\Omega$
		$V_{GS}= -2.5\text{V}$ , $I_D= -5\text{A}$	-	34	42	
<b>Dynamic Characteristics</b>						
$C_{iss}$	Input Capacitance	$V_{DS}= -10\text{V}$ , $V_{GS}=0\text{V}$ , $f=1.0\text{MHz}$	-	900	-	pF
$C_{oss}$	Output Capacitance		-	242	-	pF
$C_{rss}$	Reverse Transfer Capacitance		-	231	-	pF
$Q_g$	Total Gate Charge	$V_{DS}= -10\text{V}$ , $I_D= -3\text{A}$ , $V_{GS}= -4.5\text{V}$	-	15.3	-	nC
$Q_{gs}$	Gate-Source Charge		-	2.2	-	nC
$Q_{gd}$	Gate-Drain("Miller") Charge		-	4.4	-	nC
<b>Switching Characteristics</b>						
$t_{d(on)}$	Turn-on Delay Time	$V_{DD} = -10\text{V}$ , $I_D= -7\text{A}$ , $V_{GS}= -4.5\text{V}$ , $R_{GEN}=2.5\Omega$	-	10	-	ns
$t_r$	Turn-on Rise Time		-	31	-	ns
$t_{d(off)}$	Turn-off Delay Time		-	28	-	ns
$t_f$	Turn-off Fall Time		-	8	-	ns
<b>Drain-Source Diode Characteristics and Maximum Ratings</b>						
$I_s$	Maximum Continuous Drain to Source Diode Forward Current	-	-	-7	A	
$I_{SM}$	Maximum Pulsed Drain to Source Diode Forward Current	-	-	-28	A	
$V_{SD}$	Drain to Source Diode Forward Voltage	$V_{GS}=0\text{V}$ , $I_s= -7\text{A}$	-	-0.8	-1.2	V

Notes:1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

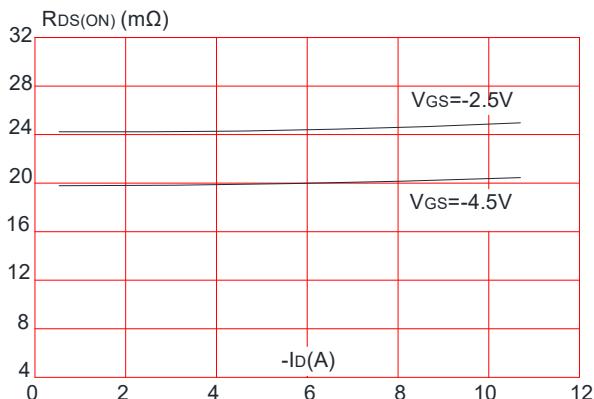
2. Pulse Test: Pulse Width $\leq 300\mu\text{s}$ , Duty Cycle $\leq 2\%$

## Typical Performance Characteristics

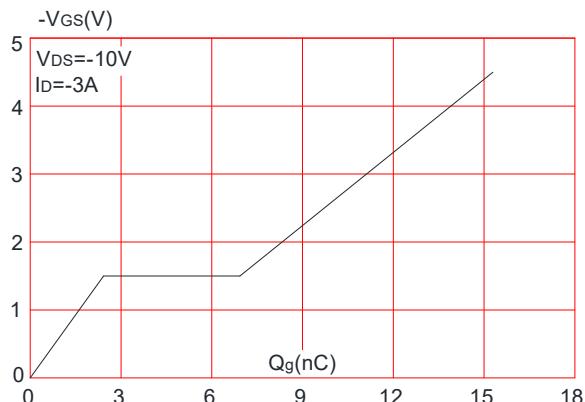
**Figure 1:** Output Characteristics



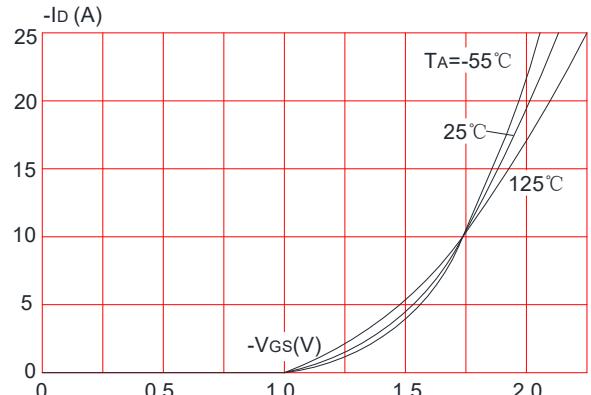
**Figure 3:** On-resistance vs. Drain Current



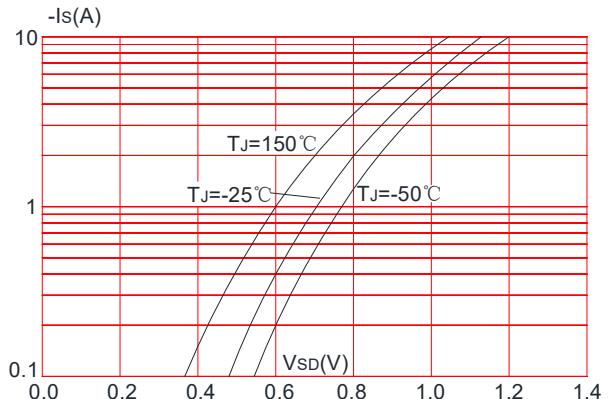
**Figure 5:** Gate Charge Characteristics



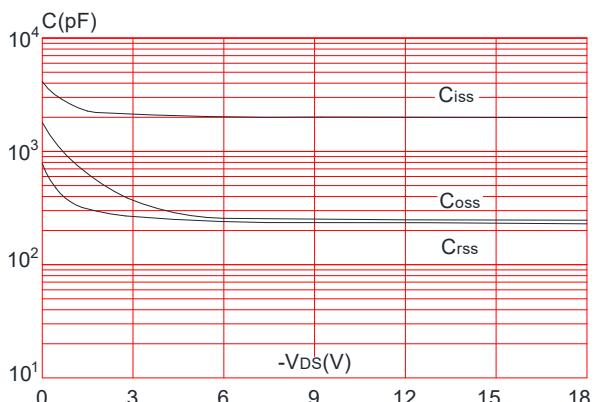
**Figure 2:** Typical Transfer Characteristics



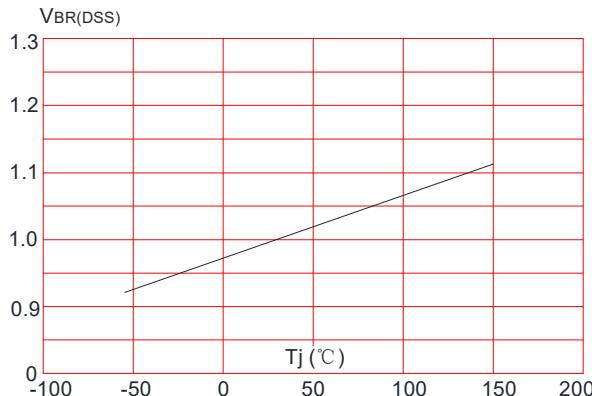
**Figure 4:** Body Diode Characteristics



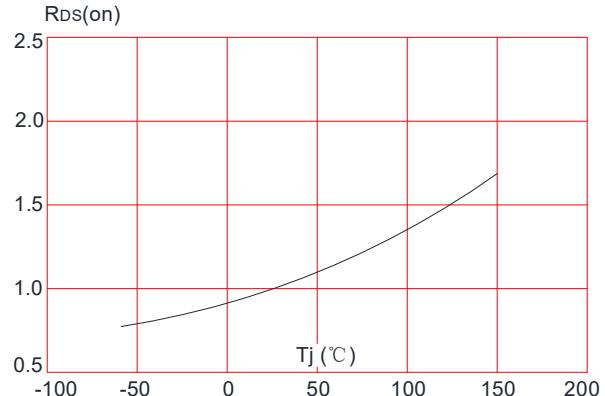
**Figure 6:** Capacitance Characteristics



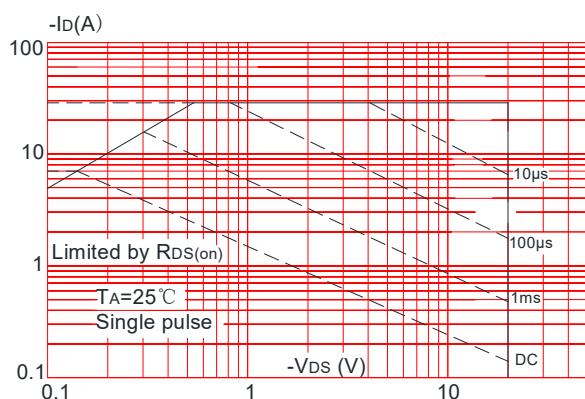
**Figure 7: Normalized Breakdown Voltage vs. Junction Temperature**



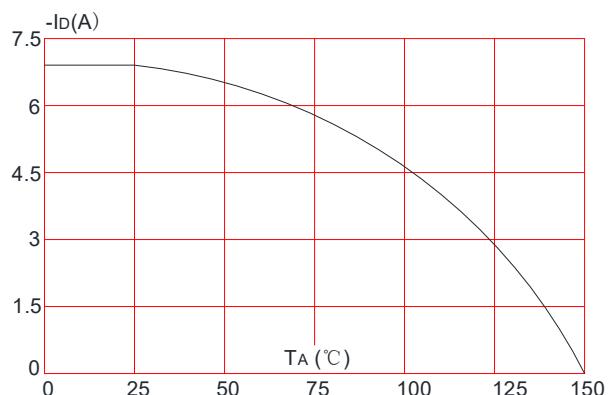
**Figure 8: Normalized on Resistance vs. Junction Temperature**



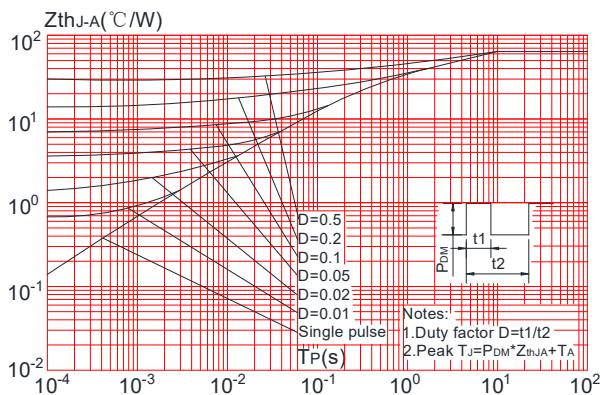
**Figure 9: Maximum Safe Operating Area**



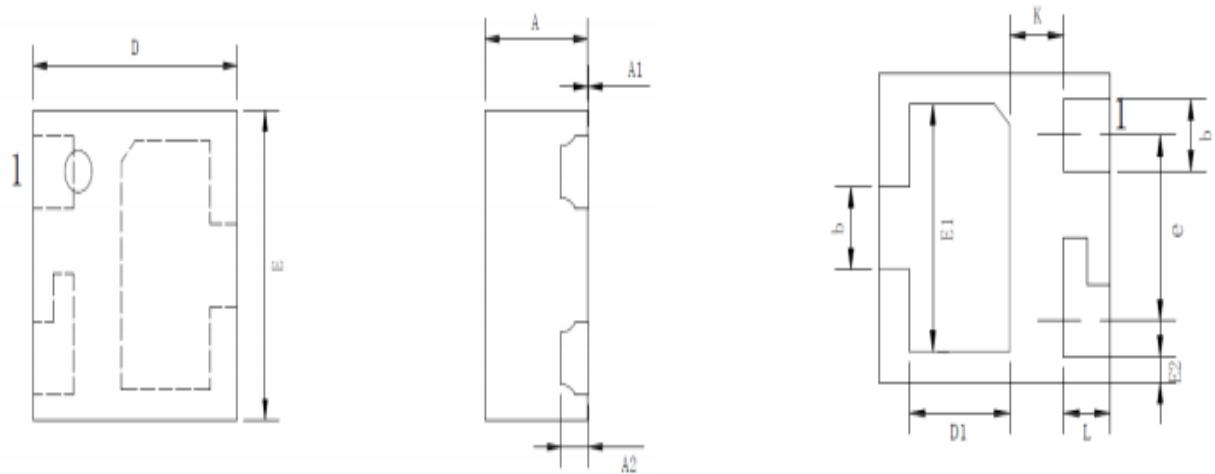
**Figure 10: Maximum Continuous Drain Current vs. Ambient Temperature**



**Figure 11: Maximum Effective Transient Thermal Impedance, Junction-to-Ambient**



## Package Information:DFN1.5x1.5-3L



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	—	—	<b>0.80</b>
A1	<b>0.00</b>	—	<b>0.05</b>
A2	<b>0.203 TIY</b>		
b	<b>0.30</b>	<b>0.35</b>	<b>0.40</b>
D	<b>1.45</b>	<b>1.50</b>	<b>1.55</b>
D1	<b>0.60</b>	<b>0.65</b>	<b>0.70</b>
E	<b>1.45</b>	<b>1.50</b>	<b>1.55</b>
E1	<b>1.15</b>	<b>1.20</b>	<b>1.25</b>
E2	<b>0.125 TIY</b>		
e	<b>0.90 BSC</b>		
K	<b>0.35 BSC</b>		
L	<b>0.25</b>	<b>0.30</b>	<b>0.35</b>